#### Lawrence Berkeley National Laboratory

#### Engineering

Title

Development of a standalone zoneplate based  $\ensuremath{\mathsf{EUV}}$  mask defect review tool

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Authors

Perera, Chami

Yoon, Gi Sung

Carlson, Ryan

<u>et al.</u>

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# Development of a standalone zoneplate based EUV mask defect review tool

Gisung Yoon, R. Carlson, B. Yang, M. Hermes Micron Technology, Inc.

<u>Chami Perera</u>, D. Houser, A. Khodarev, C. Murray, T. Grodt EUV Tech, Inc.

A. Allézy, W. Chao, F. Salmassi, E. Gullikson, P. Naulleau Center for X-ray Optics, Berkeley Lab

## Micron euv tech CXR®

#### Agenda

- Background
- System description
- Performance
- Future improvements







### BACKGROUND







#### Zoneplate microscopy proven technique for EUV mask review



#### Micron CXR()

Goldberg, et al., Proc SPIE, 9048, 90480Y (2014) Benk, et al, Proc SPIE, 10957, 109570V (2019)

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# Zoneplates are ultra-compact high wavefront quality diffractive optics



Chao, et al., Opt. Exp., 20, 9777 (2012)

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## Measurement of zoneplate aberrations in SHARP using in-situ wavefront sensor

Field dependent aberrations





SHARP

Ideal 0.33 4xNA zoneplate

Wavefront measurement

Sweet spot (Z<sub>4</sub> to Z<sub>8</sub>) : **7.2 m** $\lambda$  RMS ( $\lambda$  <sub>EUV</sub> /139)

Acron CXRO Miyakawa et. al, Proc SPIE 10143, 101430N (2017) EUV TECH

## Primary limitation of diffractive optics is chromatic aberration

- Chromatic aberration mitigated by
  - Decreased focal length
  - Decreased illumination bandwidth



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## SYSTEM DESCRIPTION







#### AIRES - ACTINIC IMAGE REVIEW SYSTEM

- Compact plasma-source zoneplate review system
- Incorporates EUV Tech's proven ultraclean mask transfer system
- Low capital cost and low cost of ownership
- Short install time
  - Roll into fab to first EUV images in < 1 month</li>

cron CXRO



US Patent 6738135B1 + Patent Pending



#### Source module

- POC tool uses Energetiq EQ10-HP DPP light source
- EUV source, vacuum system, and control system integrated into one upgradable module
- Easy access for source consumables replacements



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#### Process module

- EUV optical system consisting of collector, monochromator, illuminator, and diffractive optics
- 1200x mag direct EUV imaging
- Active vibration cancellation system
- Automated sample registration, site navigation, autofocus, and image collection
- Full diagnostics and in-situ plasma cleaning



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### Monochromator module

- Full multilayer mirror bandwidth of 2% not suitable for high quality diffractive imaging
- High efficiency, high resolution monochromator essential to plasma source application
- Measured monochromator resolution  $(\lambda/\Delta\lambda) = 470$ 
  - Design-limited performance achieved





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### PERFORMANCE







#### Flare

- Flare often raised as a concern for diffractive optical systems
- Kirk type flare test performed with 800-nm cross
- Direct measured flare = 3.1%
  - System flare < 2% after accounting for mask absorber contrast









### Uniformity

- 88-nm lines across
  3-um field
- CD uniformity +/- 1.3%
- Illumination uniformity +/- 1.8%



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#### Threshold response indicates diffraction limited performance





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#### Near theoretical contrast limit achieved



88 nm 80 nm 64 nm 72 nm

Conventional  $\sigma$  = 0.9 illumination







#### Well-controlled through focus behavior









#### Near theoretical contrast limit achieved



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### FUTURE IMPROVEMENTS







#### AIRES+

- The next generation AIRES Tool in fabrication to meet HVM Production requirements
- Increased throughput
  - Improving Optical efficiency
  - Increased source brightness
- Variable illumination
- Upgradeable to High NA
- Customer delivery scheduled Q1 2024









# Thank You